

QOS10 Series SMD OCXO, 22.1 x 25.4 x 12mm, Sine Wave/HCMOS

STANDARD SPECIFICATIONS					
Frequency	10.000 MHz, 13.000 MHz and 20.000 MHz				
Output					
Wave form	Sine Wave	HCMOS			
Level	$+4 \text{ dBm}, \pm 3 \text{ dBm}$	'0' = 10% Vcc Max., '1' = 90% VDC Typ.			
Duty Cycle	NA	50% ±5%			
Rise/ Fall time	10 nS Max. @ Frequencies < 16 Mhz, 5 nS Max. @ Frequencies > 16 Mhz.				
Stability					
Temperature	To ±0.02 ppm				
Aging 1 st year	To ±0.03 ppm				
Phase Noise (Typical)	Offset	Phase Noise			
	10 Hz	-120dBc			
	100 Hz	-140 dBc			
	1000 Hz	-145 dBc			
	10,000 Hz	-150 dBc			
Voltage control	0 Vdc to +3.3V				
Voltage control range	±0.5 ppm min., (+1.65V ±1.65VDC)				
Supply Voltage	3.3VDC ± 5%				
Supply current max.(during warm up)	1200 mA				
Supply current (typical @ 25°C)	400 mA				
Temperature					
Operating	To -40°C to +85°C (standard)				
Storage	-40°C to +85°C				

	Part Number Guide	Sample Part Numb	per: QOS100 – EQBC	3 - 20.000		
Package	Operating Temperature	Frequency Stability	Output	Voltage Control	Supply Voltage	Frequency
QOS10-	$A = 0^{\circ} C$ to $+70^{\circ} C$	$Q = \pm 0.5 \text{ ppm}$	A = Sine Wave	C = Controlled	3 = 3.3 VDC	20.000 MH
	$B = -10^{\circ} C$ to $+75^{\circ} C$	$P = \pm 0.25 \text{ ppm}$	B = 15 pF HCMOS	F = Fixed		
	$C = -20^{\circ} C$ to $+70^{\circ} C$	$N = \pm 0.1 \text{ ppm}$			- 20.000 MHz	
	$E = -40^{\circ} C$ to $+85^{\circ} C$	$M = \pm 0.02 \text{ ppm}$				



- Pin Function 1 V Control 2 N.C. 3 Vdd
- 4 Output
- 5 N.C.
- 6 N.C.
- 7 GND

Dimension Units: mm

QVS TECH INC 6965 El Camino Real, Ste 105 Carlsbad, CA 92009 Phone: (760) 929-8677 Fax: (760) 929-8077 Specifications subject to change without notice